



Product Change Notification



Product Group: DD/Wed Mar 23, 2022/PCN-DD-005-2022-REV-0

IGBT wafer diameter change in Power Modules

DESCRIPTION OF CHANGE: Change of wafer diameter of IGBT chips used in below power modules.

FROM: 6 inches wafer diameter TO: 8 inches wafer diameter

REASON FOR CHANGE: Obsolescence of 6 inches wafer from IGBT supplier.

EXPECTED INFLUENCE ON QUALITY/RELIABILITY/PERFORMANCE: There will be no effect on product quality, reliability or performance.

PART NUMBERS/SERIES/FAMILIES AFFECTED: VS-GT140DA60U, VS-GT300FD060N,

VISHAY BRAND(s): Vishay Semiconductors

TIME SCHEDULE:

Start Shipment Date: Wed Jun 1, 2022

SAMPLE AVAILABILITY: Upon request

PRODUCT IDENTIFICATION: Batch code (contact factory for the details)

QUALIFICATION DATA: Available upon request

This PCN is considered approved, without further notification, unless we receive specific customer concerns before Mon May 30, 2022 or as specified by contract.

ISSUED BY: Fabio Bertuccio, Fabio.Bertuccio@vishay.com

For further information, please contact your regional Vishay office.

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